DATA SHEET

BYD73 series

Ultra fast low-loss
controlled avalanche rectifiers

Philips
Semiconductors

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Ultra fast low-loss controlled avalanche rectifiers

BYD73 series

FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack.

DESCRIPTION

Cavity free cylindrical glass SOD81 package through Implotec™[1] technology. This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

(1) Implotec is a trademark of Philips.

Fig.1 Simplified outline (SOD81) and symbol.
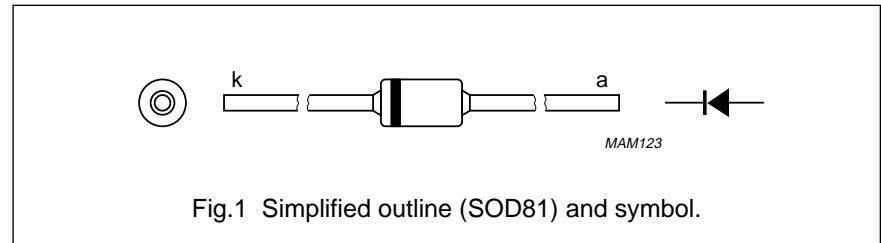
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage				
	BYD73A		–	50	V
	BYD73B		–	100	V
	BYD73C		–	150	V
	BYD73D		–	200	V
	BYD73E		–	250	V
	BYD73F		–	300	V
	BYD73G		–	400	V
V_R	continuous reverse voltage				
	BYD73A		–	50	V
	BYD73B		–	100	V
	BYD73C		–	150	V
	BYD73D		–	200	V
	BYD73E		–	250	V
	BYD73F		–	300	V
	BYD73G		–	400	V
$I_{F(AV)}$	average forward current	T_{tp} = 55 °C; lead length = 10 mm; see Figs 2 and 3; averaged over any 20 ms period; see also Figs 10 and 11			
	BYD73A to D		–	1.75	A
	BYD73E to G		–	1.70	A
$I_{F(AV)}$	average forward current	T_{amb} = 60 °C; PCB mounting (see Fig.16); see Figs 4 and 5; averaged over any 20 ms period; see also Figs 10 and 11			
	BYD73A to D		–	1.00	A
	BYD73E to G		–	0.95	A

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{FRM}	repetitive peak forward current	T_{tp} = 55 °C; see Figs 6 and 7			
	BYD73A to D		–	14	A
	BYD73E to G		–	15	A
I_{FRM}	repetitive peak forward current	T_{amb} = 60 °C; see Figs 8 and 9			
	BYD73A to D		–	8.5	A
	BYD73E to G		–	9.5	A
I_{FSM}	non-repetitive peak forward current	t = 10 ms half sine wave; T_j = $T_{j\ max}$ prior to surge; V_R = V_{RRMmax}	–	25	A
E_{RSM}	non-repetitive peak reverse avalanche energy	L = 120 mH; T_j = $T_{j\ max}$ prior to surge; inductive load switched off	–	10	mJ
T_{stg}	storage temperature		–65	+175	°C
T_j	junction temperature		–65	+175	°C

ELECTRICAL CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	I_F = 1 A; T_j = $T_{j\ max}$; see Figs 12 and 13				
	BYD73A to D		–	–	0.75	V
	BYD73E to G		–	–	0.83	V
V_F	forward voltage	I_F = 1 A; see Figs 12 and 13				
	BYD73A to D		–	–	0.98	V
	BYD73E to G		–	–	1.05	V
$V_{(BR)R}$	reverse avalanche breakdown voltage	I_R = 0.1 mA				
	BYD73A		55	–	–	V
	BYD73B		110	–	–	V
	BYD73C		165	–	–	V
	BYD73D		220	–	–	V
	BYD73E		275	–	–	V
	BYD73F		330	–	–	V
	BYD73G		440	–	–	V
I_R	reverse current	V_R = V_{RRMmax}; see Fig.14	–	–	1	μA
		V_R = V_{RRMmax}; T_j = 165 °C; see Fig.14	–	–	100	μA
t_{rr}	reverse recovery time	when switched from I_F = 0.5 A to I_R = 1 A; measured at I_R = 0.25 A; see Fig.18				
	BYD73A to D		–	–	25	ns
	BYD73E to G		–	–	50	ns

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT

C_d	diode capacitance
	    BYD73A to D
	    BYD73E to G
		$f = 1$ MHz; $V_R = 0$ V;
		see Fig.15
			–
			–
				50
				40
					–
					–
						pF
						pF

$\left\lvert\dfrac{dI_R}{dt}\right\rvert$	maximum slope of reverse recovery
	current
	    BYD73A to D
	    BYD73E to G
		when switched from
		$I_F = 1$ A to $V_R \geq 30$ V
		and $dI_F/dt = -1$ A/μs;
		see Fig.17
			–
			–
				–
				–
					4
					5
						A/μs
						A/μs

THERMAL CHARACTERISTICS

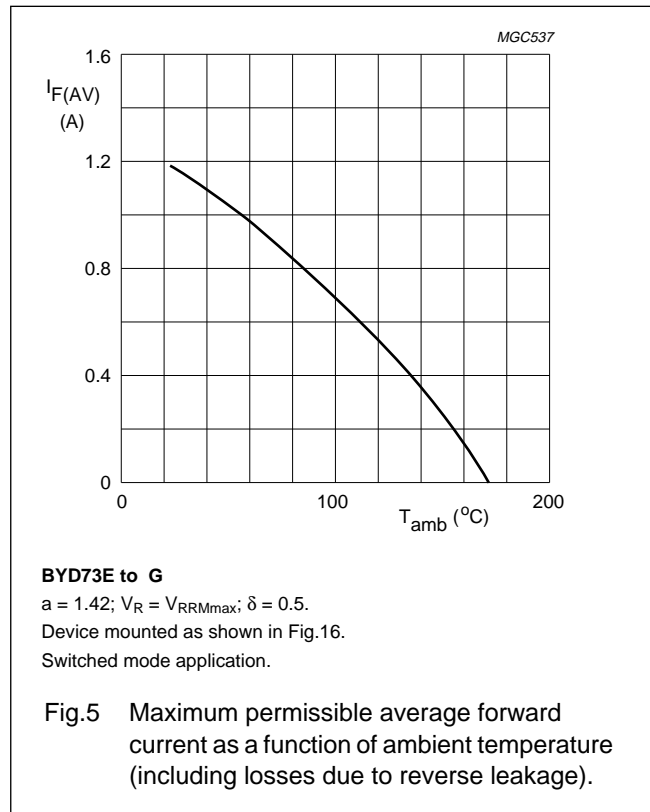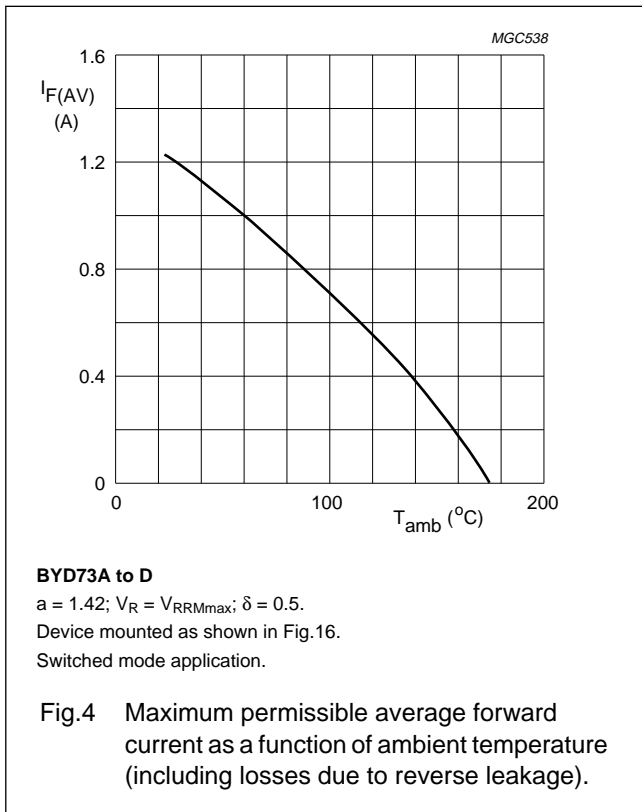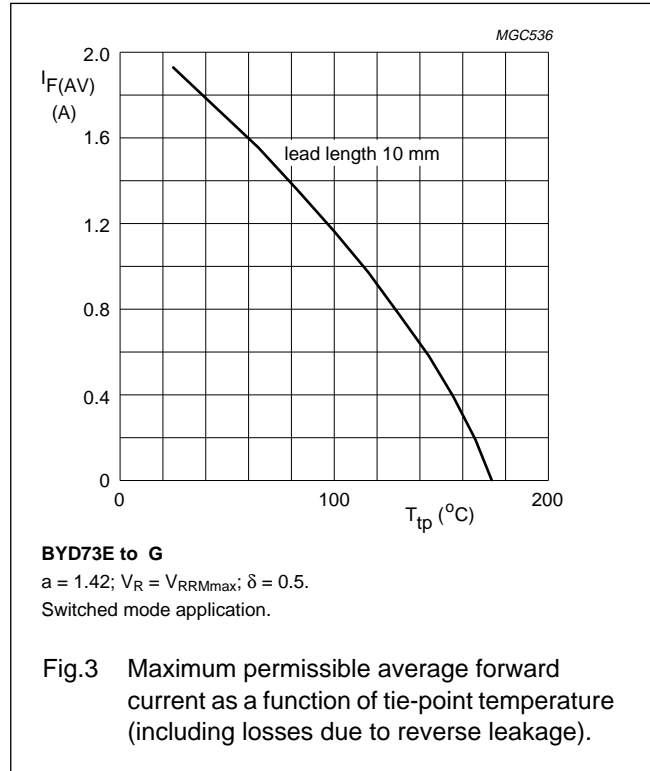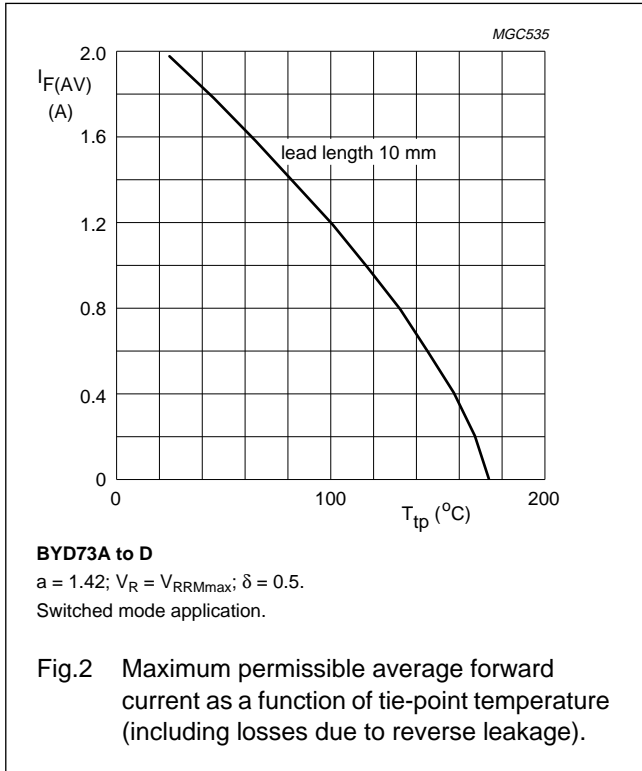| SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	60	K/W
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	120	K/W

Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer ≥40 μm, see Fig.16.
   For more information please refer to the *'General Part of Handbook SC01.'*
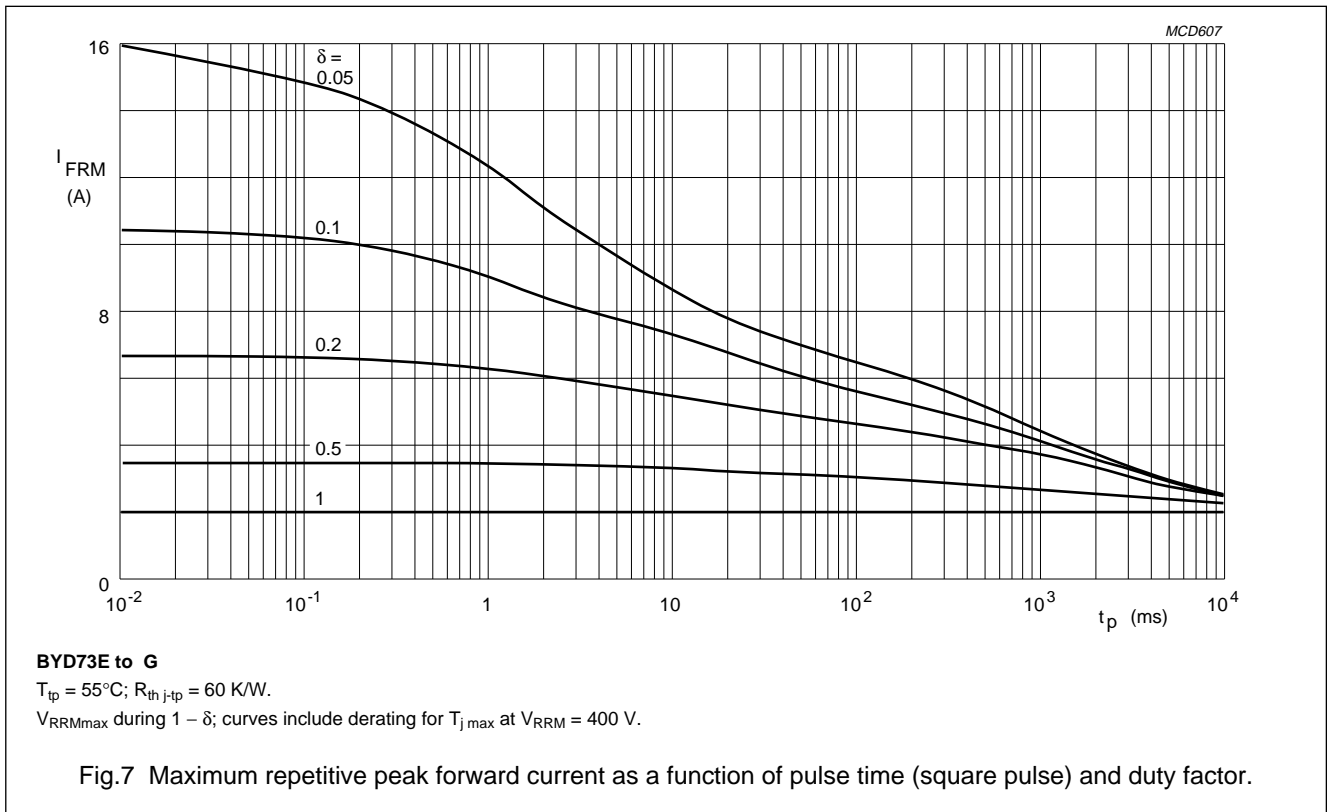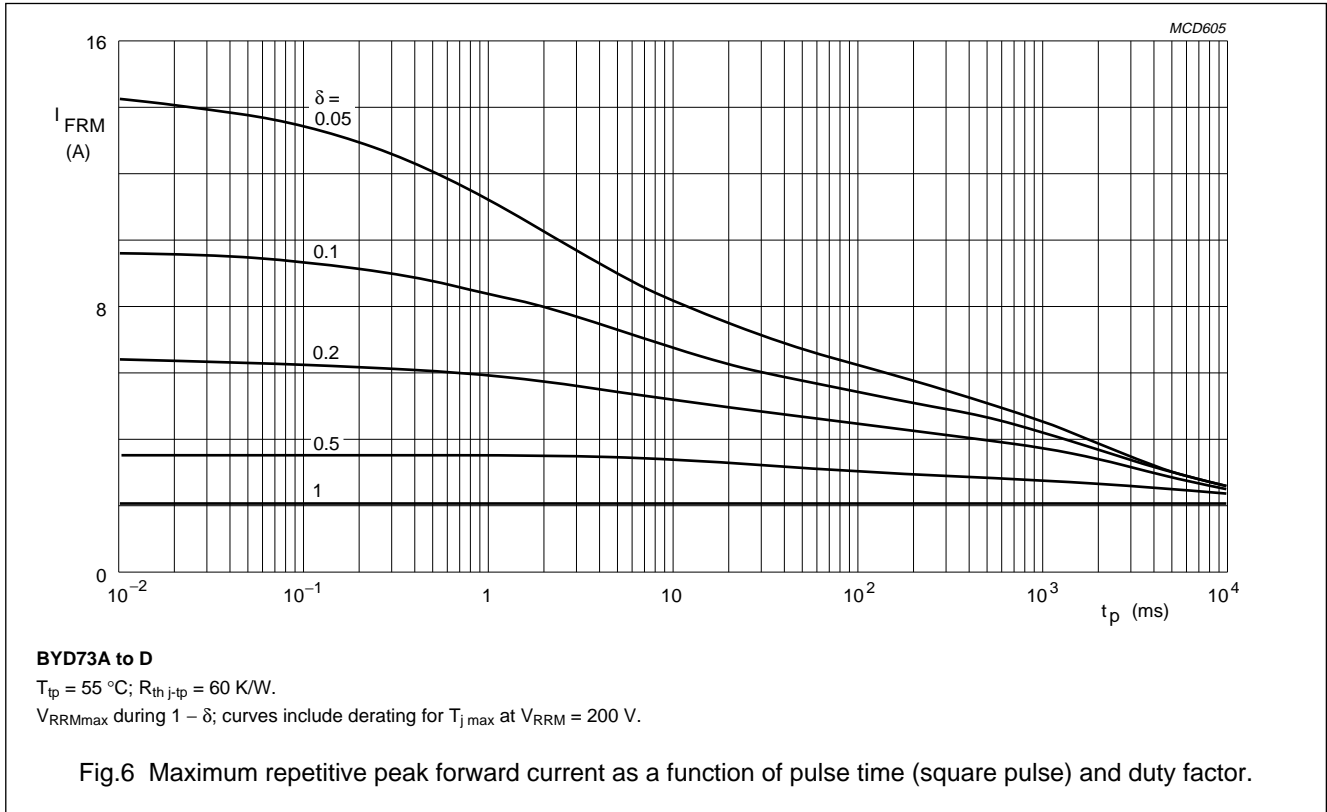
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GRAPHICAL DATA

BYD73A to D

a = 1.42; V_R = V_{RRMmax}; δ = 0.5.
Switched mode application.

Fig.2 Maximum permissible average forward
current as a function of tie-point temperature
(including losses due to reverse leakage).

BYD73E to G

a = 1.42; V_R = V_{RRMmax}; δ = 0.5.
Switched mode application.

Fig.3 Maximum permissible average forward
current as a function of tie-point temperature
(including losses due to reverse leakage).

BYD73A to D

a = 1.42; V_R = V_{RRMmax}; δ = 0.5.
Device mounted as shown in Fig.16.
Switched mode application.

Fig.4 Maximum permissible average forward
current as a function of ambient temperature
(including losses due to reverse leakage).

BYD73E to G

a = 1.42; V_R = V_{RRMmax}; δ = 0.5.
Device mounted as shown in Fig.16.
Switched mode application.

Fig.5 Maximum permissible average forward
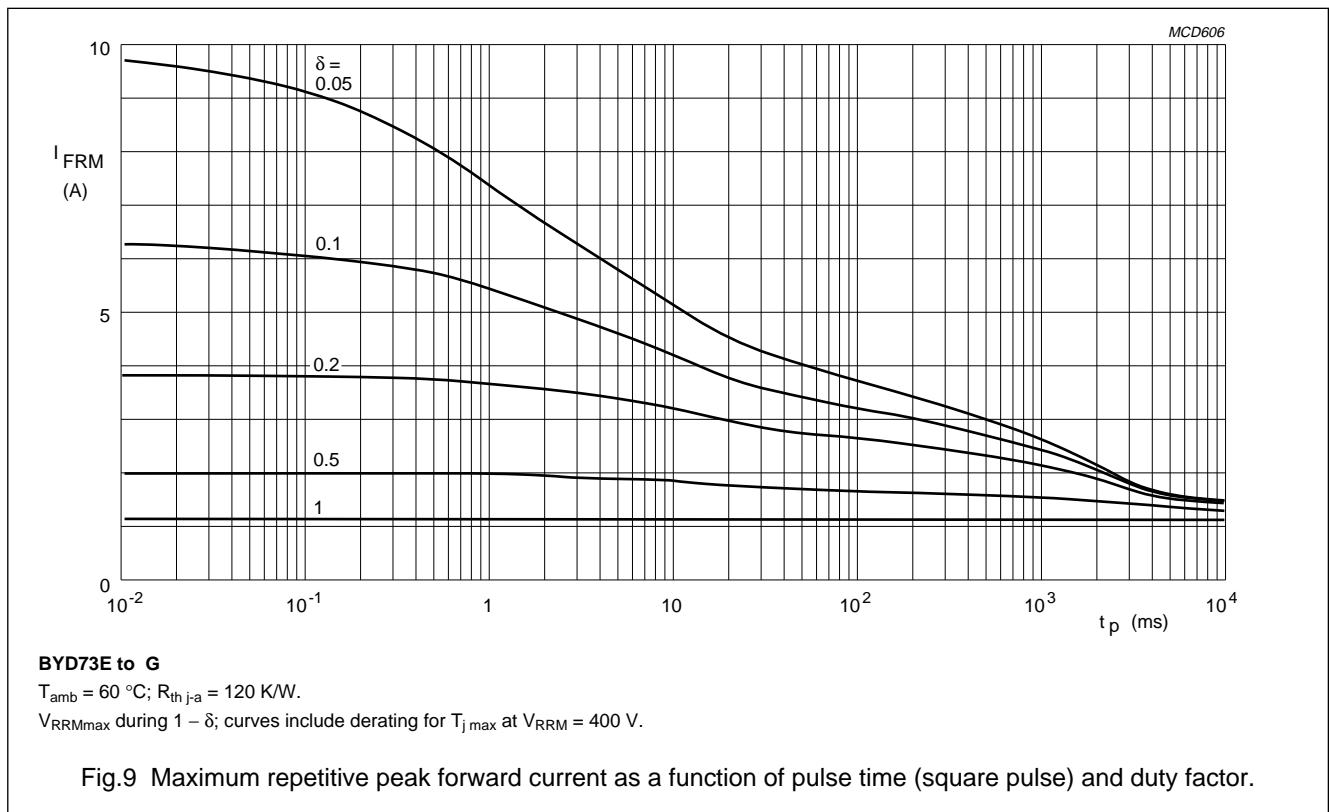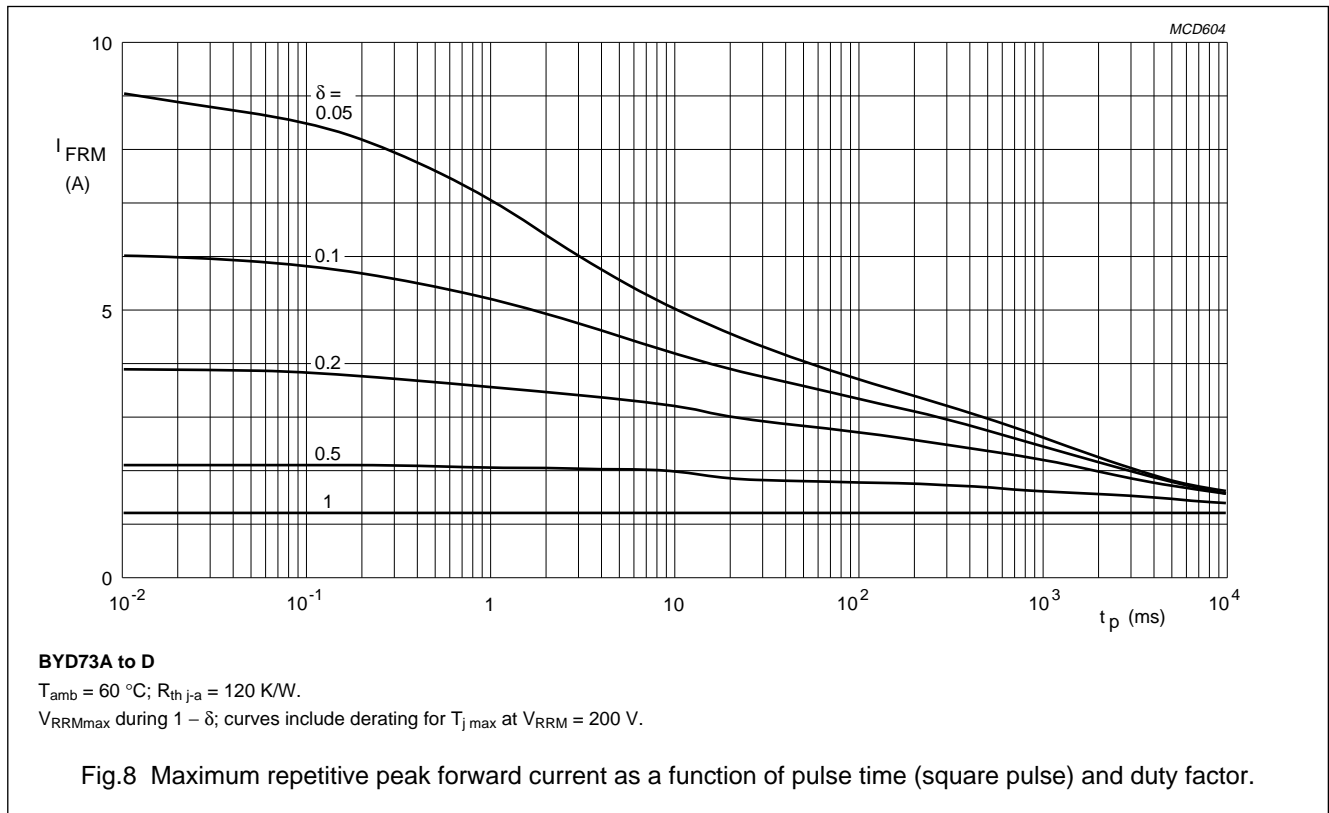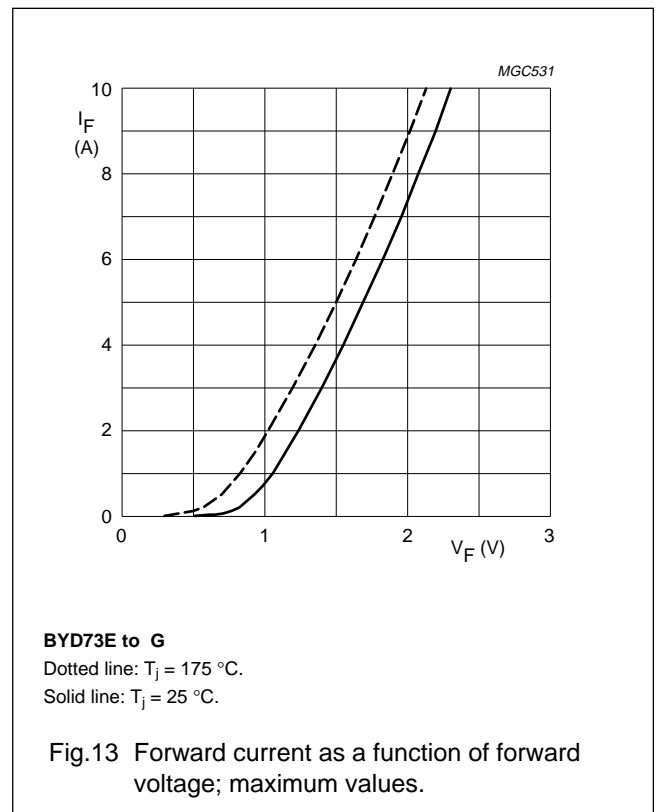current as a function of ambient temperature
(including losses due to reverse leakage).

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MCD605

BYD73A to D

T_{tp} = 55 °C; $R_{th \, j\text{-}tp}$ = 60 K/W.

V_{RRMmax} during $1 - \delta$; curves include derating for $T_{j \, max}$ at V_{RRM} = 200 V.

Fig.6 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

MCD607

BYD73E to G

T_{tp} = 55°C; $R_{th \, j\text{-}tp}$ = 60 K/W.

V_{RRMmax} during $1 - \delta$; curves include derating for $T_{j \, max}$ at V_{RRM} = 400 V.

Fig.7 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

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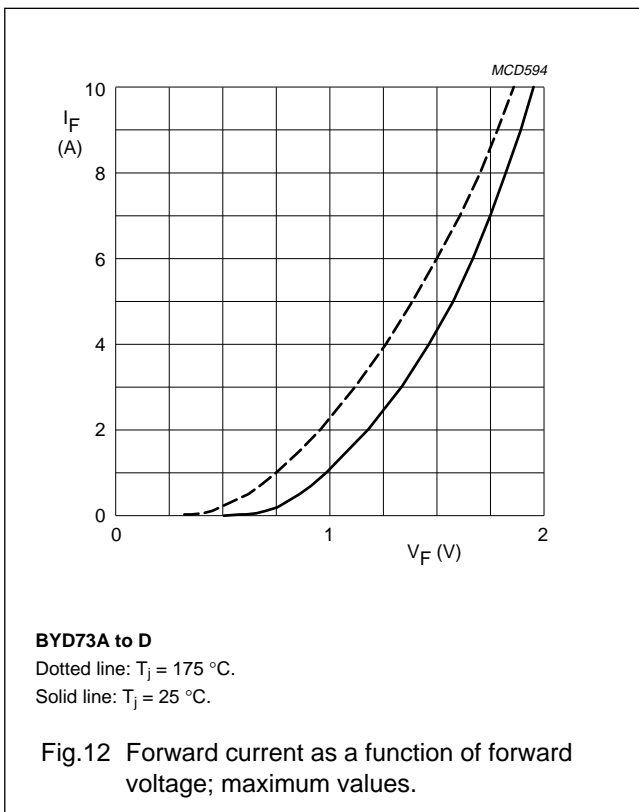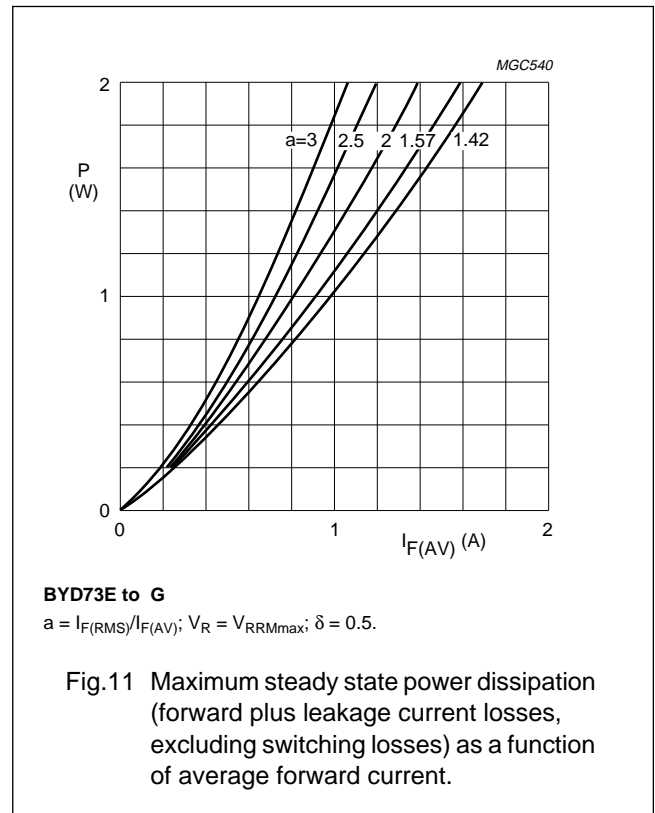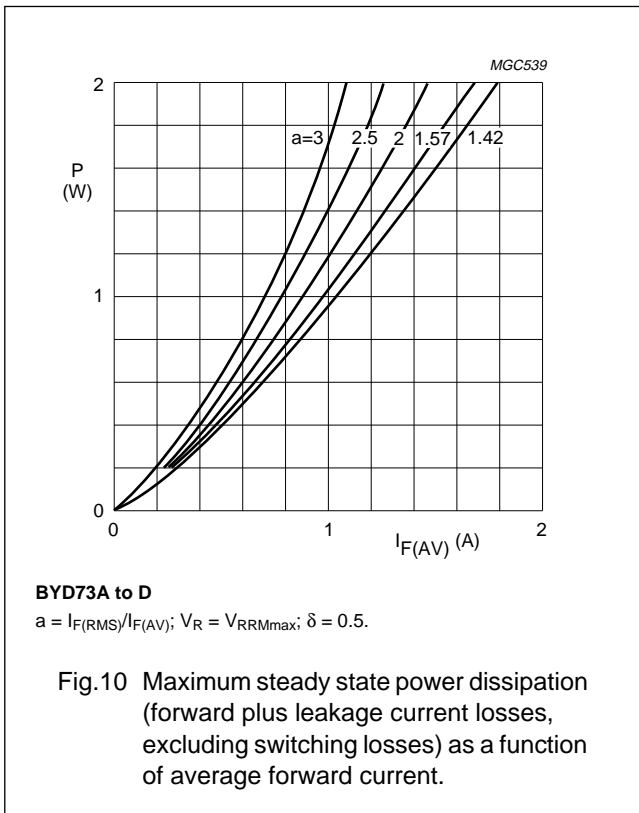controlled avalanche rectifiers

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MCD604

BYD73A to D

$T_{amb} = 60\ ^\circ C$; $R_{th\ j\text{-}a} = 120$ K/W.

V_{RRMmax} during $1 - \delta$; curves include derating for $T_{j\ max}$ at $V_{RRM} = 200$ V.

Fig.8 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

MCD606

BYD73E to G

$T_{amb} = 60\ ^\circ C$; $R_{th\ j\text{-}a} = 120$ K/W.

V_{RRMmax} during $1 - \delta$; curves include derating for $T_{j\ max}$ at $V_{RRM} = 400$ V.

Fig.9 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.
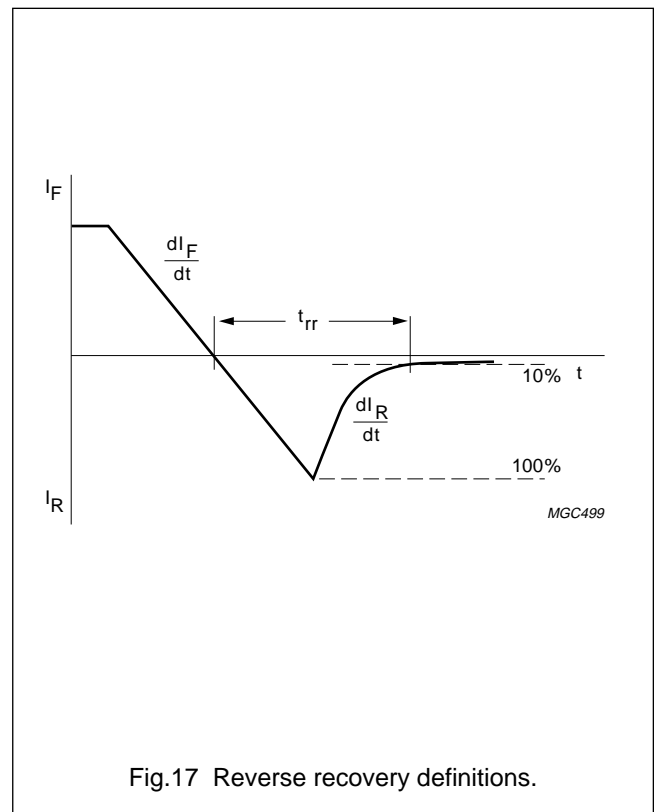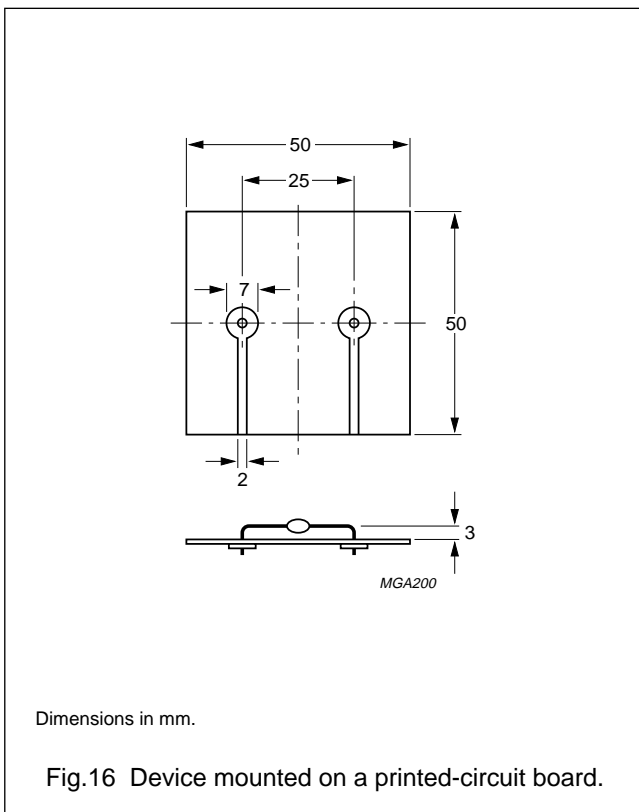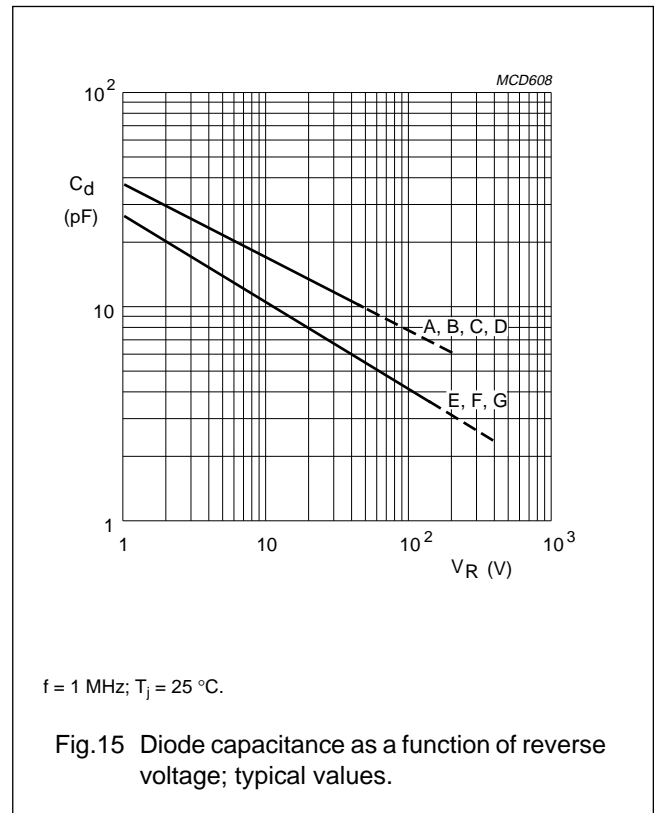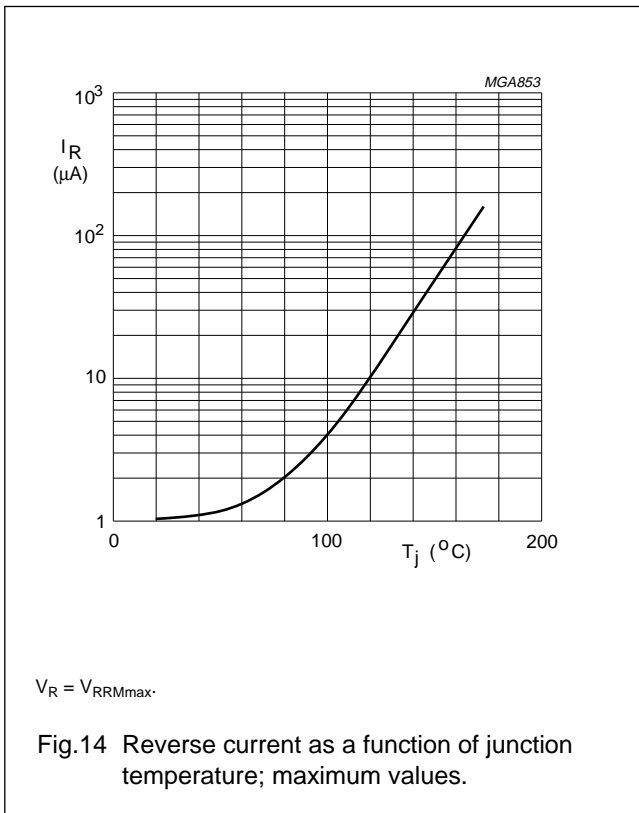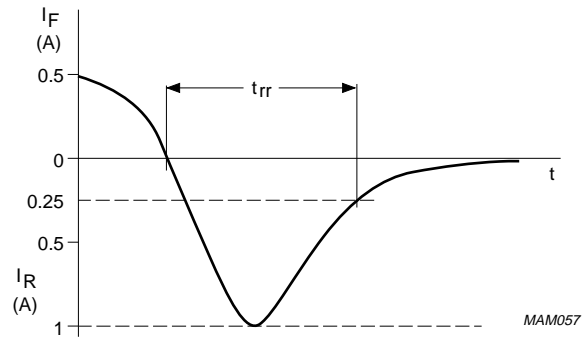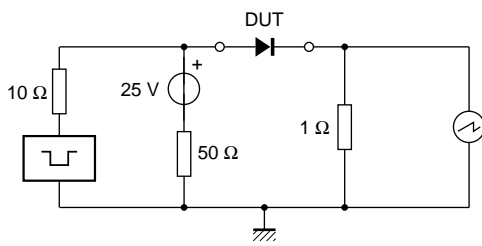
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BYD73A to D

$a = I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RRMmax}$; $\delta = 0.5$.

Fig.10 Maximum steady state power dissipation
(forward plus leakage current losses,
excluding switching losses) as a function
of average forward current.

BYD73E to G

$a = I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RRMmax}$; $\delta = 0.5$.

Fig.11 Maximum steady state power dissipation
(forward plus leakage current losses,
excluding switching losses) as a function
of average forward current.

BYD73A to D

Dotted line: $T_j = 175\ °C$.
Solid line: $T_j = 25\ °C$.

Fig.12 Forward current as a function of forward
voltage; maximum values.

BYD73E to G

Dotted line: $T_j = 175\ °C$.
Solid line: $T_j = 25\ °C$.

Fig.13 Forward current as a function of forward
voltage; maximum values.

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$V_R = V_{RRMmax}$.

Fig.14 Reverse current as a function of junction temperature; maximum values.

$f = 1$ MHz; $T_j = 25$ °C.

Fig.15 Diode capacitance as a function of reverse voltage; typical values.

Dimensions in mm.

Fig.16 Device mounted on a printed-circuit board.

Fig.17 Reverse recovery definitions.

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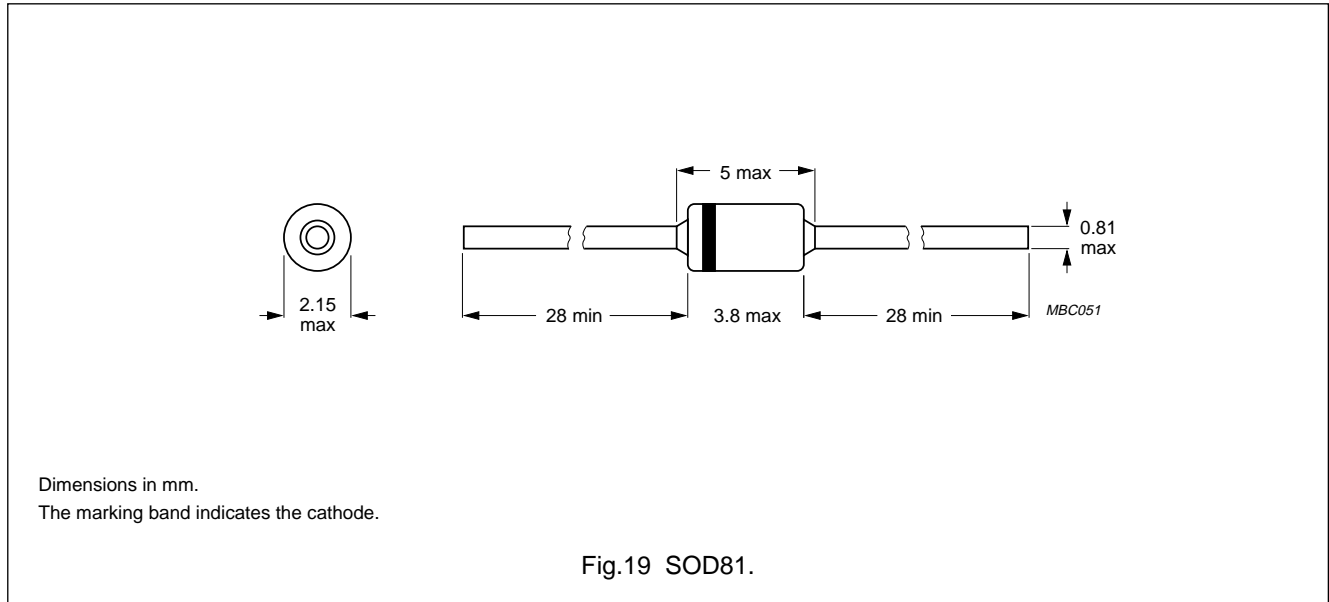controlled avalanche rectifiers

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Input impedance oscilloscope: 1 MΩ, 22 pF; $t_r \leq 7$ ns.

Source impedance: 50 Ω; $t_r \leq 15$ ns.

Fig.18 Test circuit and reverse recovery time waveform and definition.

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PACKAGE OUTLINE

Dimensions in mm.
The marking band indicates the cathode.

Fig.19 SOD81.

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.